## NSN 5961-01-474-3667

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-474-3667 **Inclosure Material:** Ceramic **Overall Length:** Between 2.140 inches and 2.785 inches **Overall Width:** Between 0.085 inches and 0.140 inches **Features Provided:** Hermetically sealed case Voltage Rating In Volts Per Characteristic: 6.7 breakdown voltage, dc **Current Rating Per Characteristic:** 50.00 microamperes forward current, average torr **Special Features:** Low dynamic impedance; hermetically sealed in metoxillite fused metal oxide; 500 watt peak pulse power; 1.5 watt continuous; axial leaded; high reliability Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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